NEC

PNP SILICON POWER TRANSISTOR 2SB1217

DESCRIPTION

The 2SB1217 is a Low V_{CE(sat)} transistor which has a large

current capability and wide SOA.

It is suitable for DC-DC converter, or driver of solenoid or

motor.

FEATURES

Low Collector Saturation Voltage.

 $V_{CE(sat)} = -0.3 \text{ V MAX.} (@I_{C}/I_{B} = -1.5 \text{ A}/-0.15 \text{ A})$

Large Current

 $I_{C(DC)} = -3.0 \text{ A}, I_{C(pulse)} = -5.0 \text{ A}$

- High Total Power Dissipation.: P_T = 1.3W
- Complementary to 2SD1818

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures

Storage Temperature -55 to +150 °C

Junction Temperature +150 °C Maximum

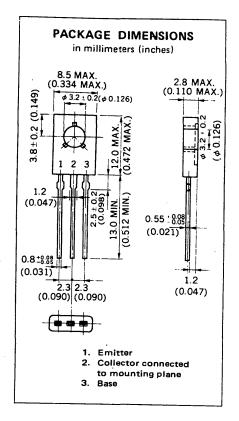
Maximum Power Dissipations

Total Power Dissipation ($T_a = 25 \,^{\circ}\text{C}$) . . . 1.3 W Total Power Dissipation ($T_c = 25 \,^{\circ}\text{C}$) . . . 10 W

Maximum Voltages and Currents (Ta = 25 °C)

V_{CBO} Collector to Base Voltage -60 VCEO Collector to Emitter Voltage . . -60 V VEBO Emitter to Base Voltage -7.0Collector Current IC(DC) -3.0Α I_{C(pulse)} * Collector Current -5.0 B(DC)

*PW \leq 10 μ s, Duty Cycle \leq 50 %



ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
VCE(sat)**	Collector Saturation Voltage		-0.2	-0.3	V	I _C = -1.5 A, I _B = -0.15 A
V _{BE(sat)} **	Base Saturation Voltage		-0.9	-1.2	V	I _C = -1.5 A, I _B = -0.15 A
hFE1**	DC Current Gain	60			_	$V_{CE} = -2.0 \text{ V, } I_{C} = -0.2 \text{ A}$
hFE2**	DC Current Gain	100		400	_	$V_{CE} = -2.0 \text{ V}, I_{C} = -0.6 \text{ A}$
hFE3**	DC Current Gain	50				V _{CE} = -2.0 V, I _C = -2.0 A
ІСВО	Collector Cutoff Current			-10	μΑ	$V_{CB} = -60 \text{ V, I}_{E} = 0$
^I EBO	Emitter Cutoff Current			-10	μΑ	$V_{EB} = -7.0 V, I_{C} = 0$
ton	Turn-On Time		0.15	0.5	μs	
t _{stg}	Storage Time		0.5	2.0	μs	$I_C = -1.0 \text{ A, } I_{B1} = -I_{B2} = -0.1 \text{ A}$ $R_L = 10 \Omega, V_{CC} = -10 \text{ V}$
tf	Fall Time		0.1	0.5	μs	

^{**}PW \leq 350 μ s, Duty Cycle \leq 2 %

Classification of hFE2

Rank	М	L	К
Range	100 to 200	160 to 320	200 to 400

Test Conditions $V_{CE} = -2.0 \text{ V}$, $I_{C} = -0.6 \text{ A}$

TYPICAL CHARACTERISTICS (Ta = 25 °C)

